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# FGH80N60FD2

## 600 V Field Stop IGBT

### Features

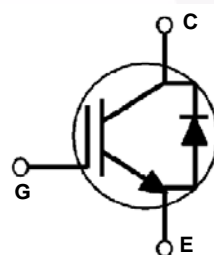
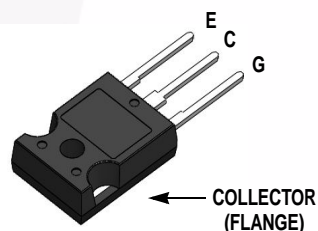
- High Current Capability
- Low Saturation Coltage:  $V_{CE(sat)} = 1.8\text{ V @ } I_C = 40\text{ A}$
- High Input Impedance
- Fast Switching
- RoHS Compliant

### Applications

- Induction Heating, PFC

### General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for induction heating and PFC applications where low conduction and switching losses are essential.



### Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	600	V
$V_{GES}$	Gate-Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	80	A
	Collector Current @ $T_C = 100^\circ\text{C}$	40	A
$I_{CM}$ (1)	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	160	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	290	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	116	W
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

**Notes :**

(1) Repetitive rating : Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction-to-Case	--	0.43	$^\circ\text{C/W}$
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction-to-Case	--	1.45	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	--	40	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH80N60FD2TU	FGH80N60FD2	TO-247	Tube	N/A	N/A	30

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

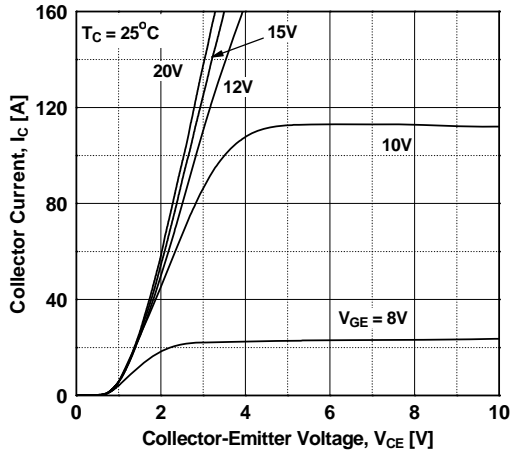
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
BV <sub>CES</sub>	Collector-Emitter Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA	600	--	--	V
ΔBV <sub>CES</sub> / ΔT <sub>J</sub>	Temperature Coefficient of Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA	--	0.6	--	V/°C
I <sub>CES</sub>	Collector Cut-Off Current	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V	--	--	250	μA
I <sub>GES</sub>	G-E Leakage Current	V <sub>GE</sub> = V <sub>GES</sub> , V <sub>CE</sub> = 0 V	--	--	±400	nA
<b>On Characteristics</b>						
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 250 μA, V <sub>CE</sub> = V <sub>GE</sub>	4.5	5.5	7.0	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	--	1.8	2.4	V
		I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V, T <sub>C</sub> = 125°C	--	2.05	--	V
<b>Dynamic Characteristics</b>						
C <sub>ies</sub>	Input Capacitance	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V, f = 1 MHz	--	2110	--	pF
C <sub>oes</sub>	Output Capacitance		--	200	--	pF
C <sub>res</sub>	Reverse Transfer Capacitance		--	60	--	pF
<b>Switching Characteristics</b>						
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 40 A, R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 25°C	--	21	--	ns
t <sub>r</sub>	Rise Time		--	56	--	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		--	126	--	ns
t <sub>f</sub>	Fall Time		--	50	100	ns
E <sub>on</sub>	Turn-On Switching Loss		--	1	1.5	mJ
E <sub>off</sub>	Turn-Off Switching Loss		--	0.52	0.78	mJ
E <sub>ts</sub>	Total Switching Loss	--	1.52	2.28	mJ	
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 40 A, R <sub>G</sub> = 10 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 125°C	--	20	--	ns
t <sub>r</sub>	Rise Time		--	54	--	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		--	131	--	ns
t <sub>f</sub>	Fall Time		--	70	--	ns
E <sub>on</sub>	Turn-On Switching Loss		--	1.1	--	mJ
E <sub>off</sub>	Turn-Off Switching Loss		--	0.78	--	mJ
E <sub>ts</sub>	Total Switching Loss	--	1.88	--	mJ	
Q <sub>g</sub>	Total Gate Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V	--	120	--	nC
Q <sub>ge</sub>	Gate-Emitter Charge		--	14	--	nC
Q <sub>gc</sub>	Gate-Collector Charge		--	58	--	nC

**Electrical Characteristics of the Diode**  $T_C = 25^\circ\text{C}$  unless otherwise noted

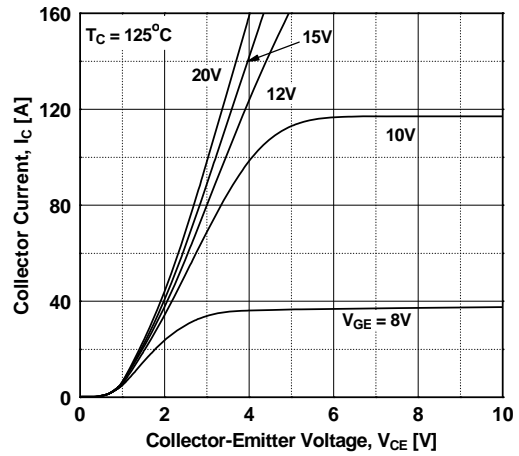
Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Unit	
$V_{FM}$	Diode Forward Voltage	$I_F = 15\text{ A}$	$T_C = 25^\circ\text{C}$	-	1.2	1.5	V
			$T_C = 125^\circ\text{C}$	-	1.0	-	
$t_{rr}$	Diode Reverse Recovery Time	$I_F = 15\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	-	61	-	ns
			$T_C = 125^\circ\text{C}$	-	125	-	
$I_{rr}$	Diode Reverse Recovery Current	$I_F = 15\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	-	4.8	-	A
			$T_C = 125^\circ\text{C}$	-	8.4	-	
$Q_{rr}$	Diode Reverse Recovery Charge	$I_F = 15\text{ A},$ $di_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 25^\circ\text{C}$	-	146	-	nC
			$T_C = 125^\circ\text{C}$	-	525	-	

## Typical Performance Characteristics

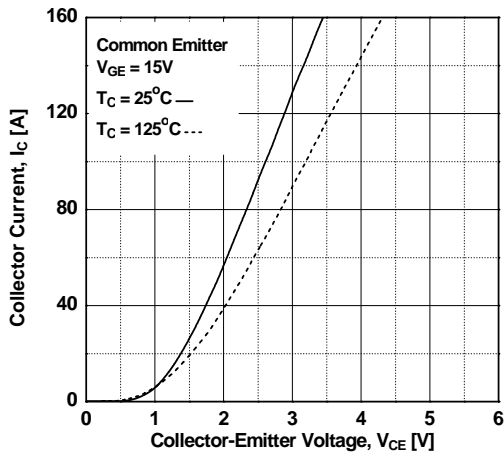
**Figure 1. Typical Output Characteristics**



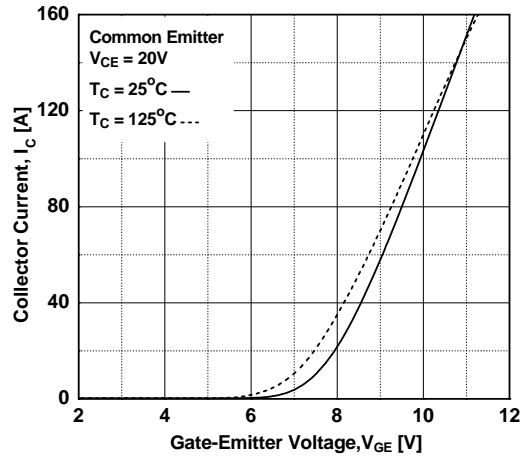
**Figure 2. Typical Saturation Voltage Characteristics**



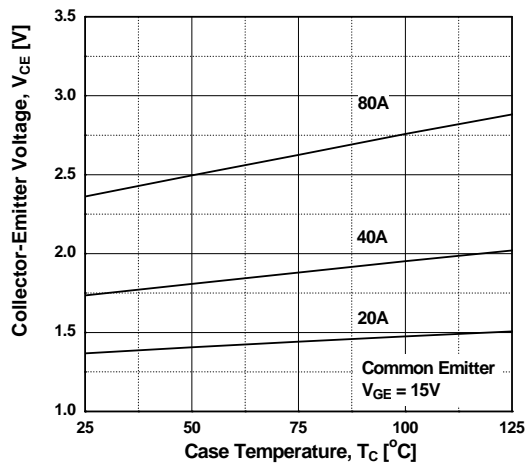
**Figure 3. Typical Saturation Voltage Characteristics**



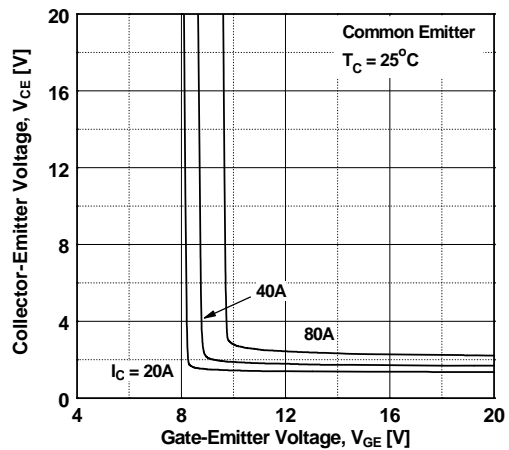
**Figure 4. Transfer Characteristics**



**Figure 5. Saturation Voltage vs. Case**

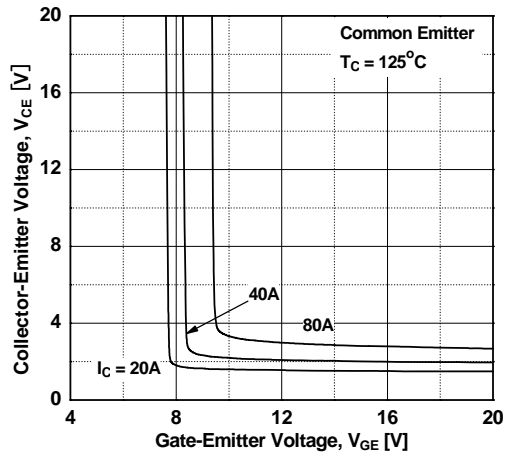


**Figure 6. Saturation Voltage vs. Vge**

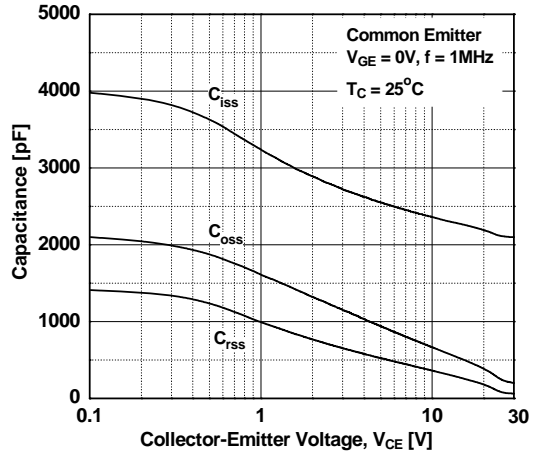


**Typical Performance Characteristics** (Continued)

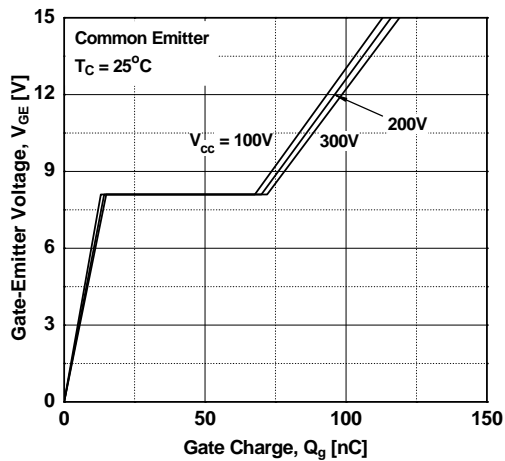
**Figure 7. Saturation Voltage vs. V<sub>GE</sub>**



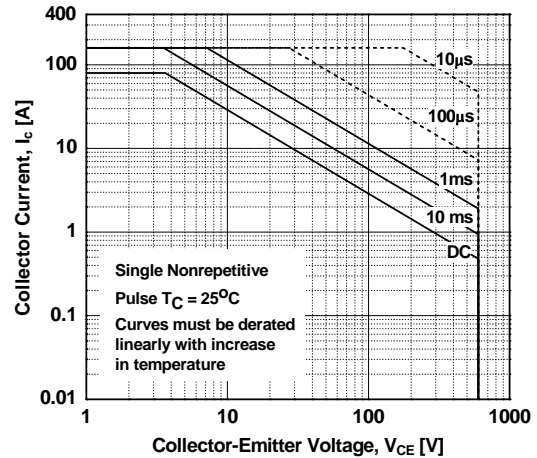
**Figure 8. Capacitance Characteristics**



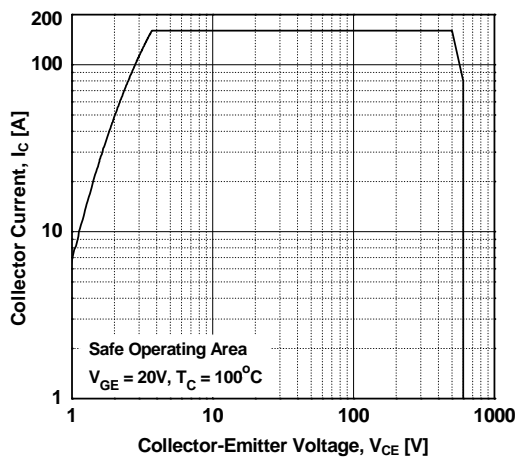
**Figure 9. Gate Charge Characteristics**



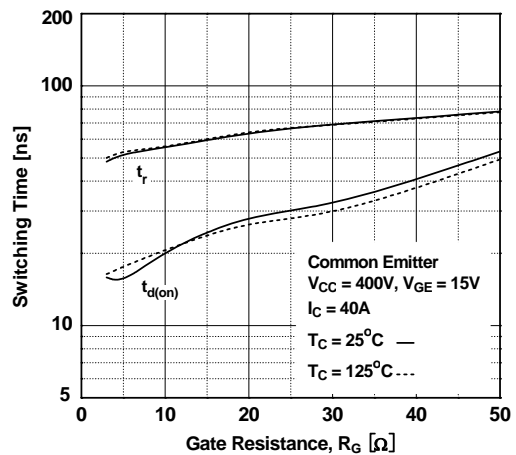
**Figure 10. SOA Characteristics**



**Figure 11. Turn-Off Switching SOA Characteristics**

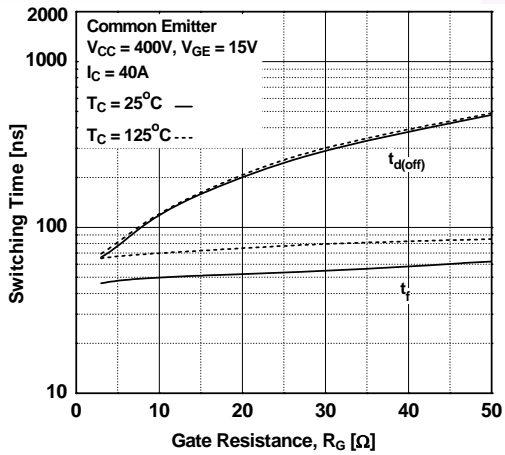


**Figure 12. Turn-On Characteristics vs. Gate Resistance**

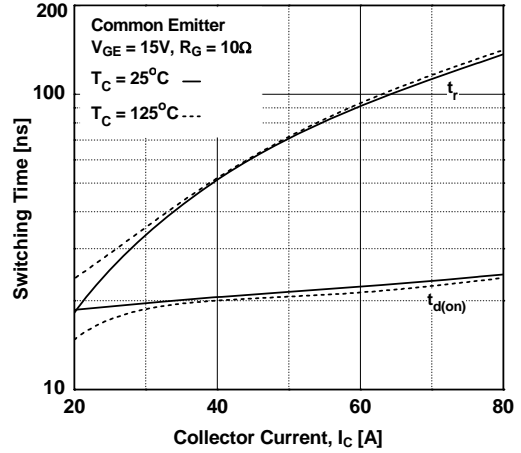


**Typical Performance Characteristics** (Continued)

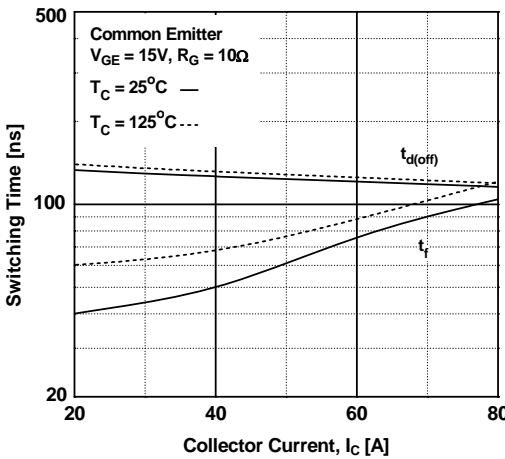
**Figure 13. Turn-Off Characteristics vs. Gate Resistance**



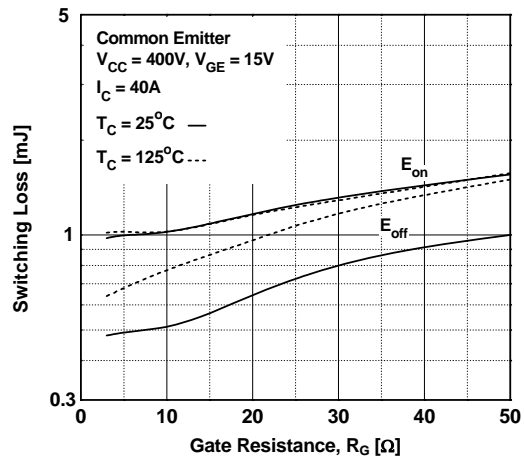
**Figure 14. Turn-On Characteristics vs. Collector Current**



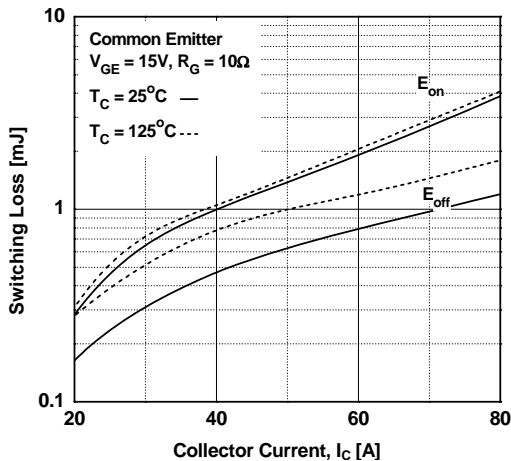
**Figure 15. Turn-Off Characteristics vs. Collector Current**



**Figure 16. Switching Loss vs Gate Resistance**

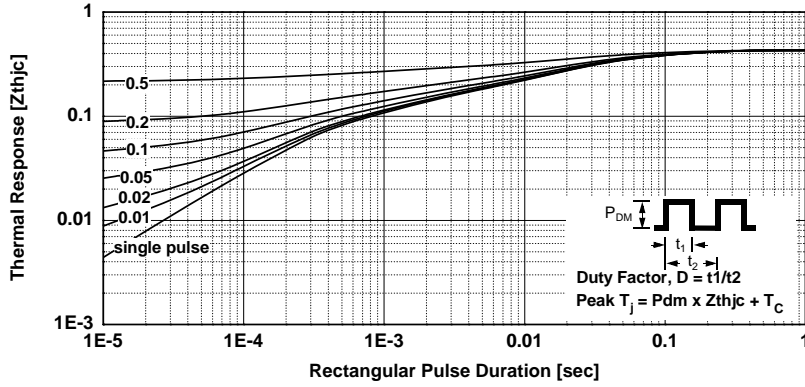


**Figure 17. Switching Loss vs Collector Current**

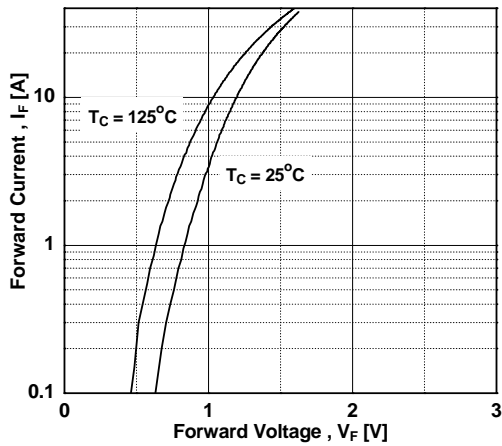


**Typical Performance Characteristics** (Continued)

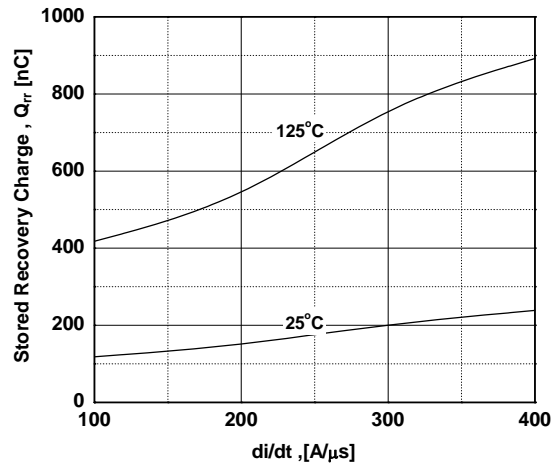
**Figure 18. Transient Thermal Impedance of IGBT**



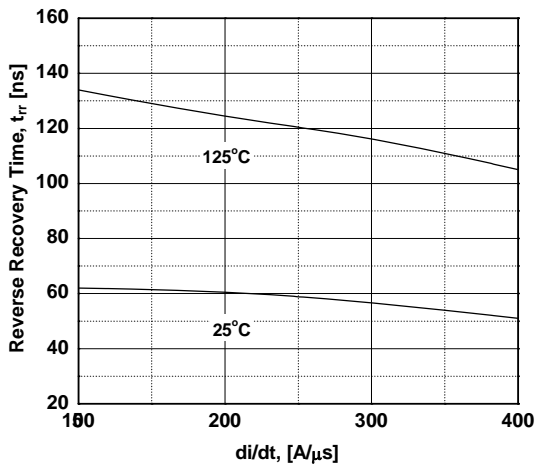
**Figure 19. Forward Characteristics**



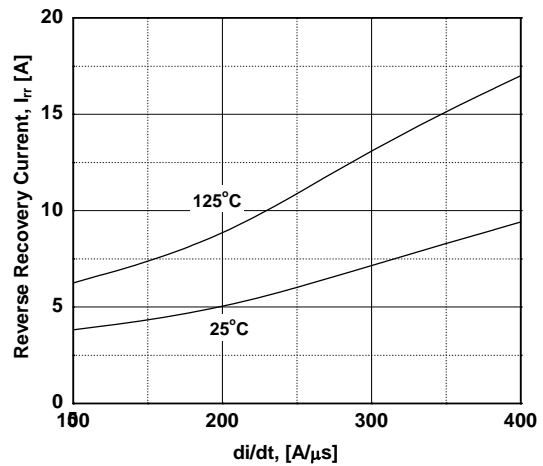
**Figure 20. Stored Charge**



**Figure 21. Reverse Recovery Time**

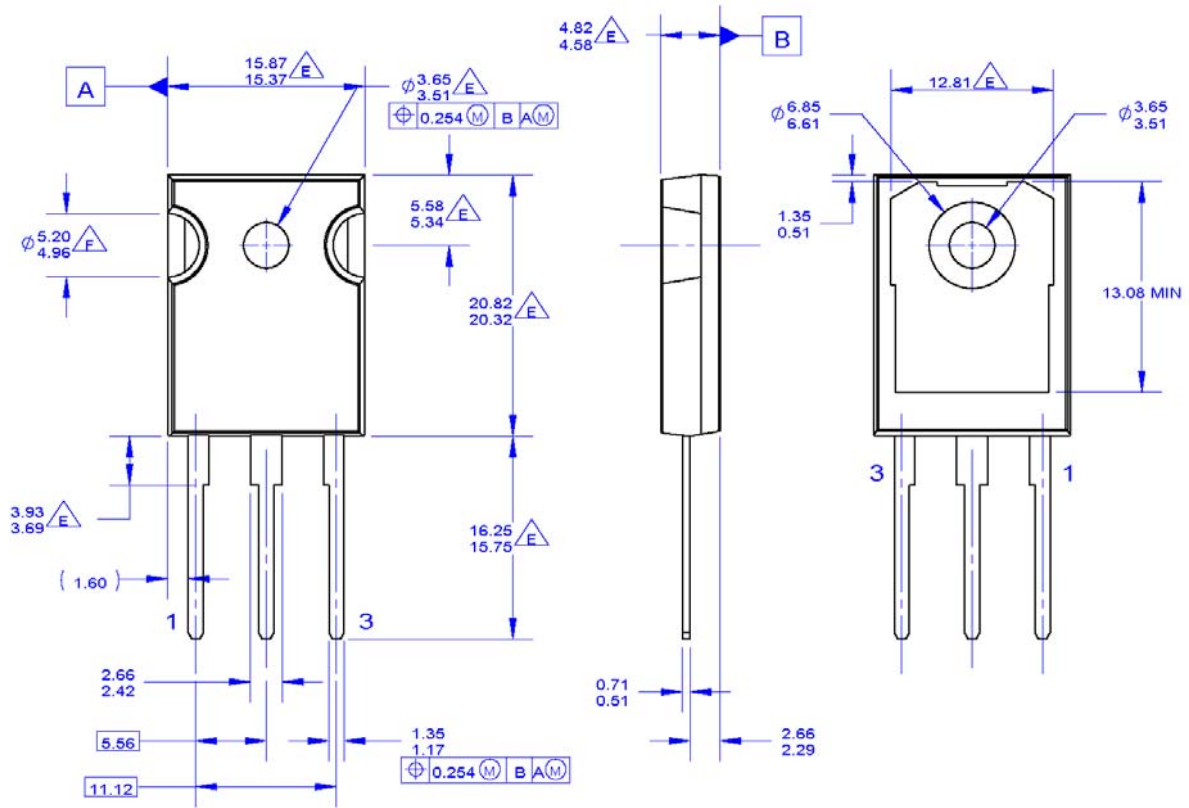


**Figure 22. Reverse Recovery Current**





**Mechanical Dimensions**



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- NOTCH MAY BE SQUARE
- G. DRAWING FILENAME: MKT-TO247A03\_REV03

**Figure 23. TO-247 3L - TO-247,MOLDED,3 LEAD,JEDEC VARIATION AB**

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